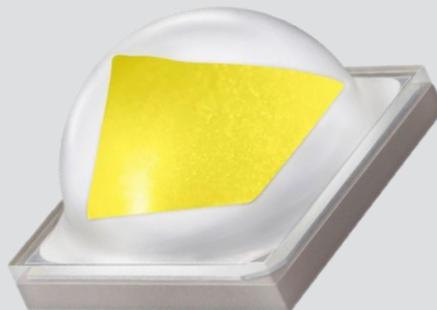


High Power LED Series 3535 Ceramic Hot Binning

LH351C



High efficacy and high quality color rendering makes the LH351C suitable use in a broad range of applications



Features & Benefits

- Operates at a maximum current of up to 2 A
- Uniform light distribution under any beam angle
- 90 CRI makes it well suited for most applications
- Hot binning @ 85 °C

Applications

- Indoor Lighting: Spotlight, Downlight
- Outdoor Lighting: Street Light, Tunnel Light, Security Light, Area Light, Stadium/Arena Light
- Industrial Lighting: High Bay Light, Low Bay Light
- Consumer Lighting: Torch Light

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1. Characteristics

a) Absolute Maximum Rating

Item	Symbol	Rating	Unit	Condition
Operating Temperature	T_{opr}	-40 ~ +105	°C	Note 1)*
Storage Temperature	T_{stg}	-40 ~ +120	°C	-
LED Junction Temperature	T_j	150	°C	-
Forward Current	I_F	2000	mA	-
Peak Pulse Forward Current	I_{FP}	2600	mA	Duty 1/10 pulse width 10ms
Assembly Process Temperature		260 <10	°C s	-
ESD (HBM)	-	±8	kV	-

Notes:

- 1) Refer to the derating curve, '3. Typical Characteristics Graph', for proper driving current that maintained below maximum junction temperature.

b) Electro-optical Characteristics

Item	Unit	Nominal CCT (K)	Condition		Value Typ.
			I _F (mA)	T _J (°C)	
Luminous Flux (Φ _v)	lm	4000 (70 CRI)	350	85	173
			700	25	355
			700	85	320
			1050	85	448
			1500	85	579
			2000	85	685
Forward Voltage (V _F)	V		350	85	2.76
			700	25	3.01
			700	85	2.90
			1050	85	3.01
			1500	85	3.11
			2000	85	3.18
Reverse Voltage (@ 5 mA)	V		25	11~15	
Thermal Resistance (junction to solder point)	°C/W		25	3	
Beam Angle	°		700	25	128

Notes:

- 1) Samsung maintains measurement tolerance of: luminous flux = ±7 %, forward voltage = ±0.1 V
- 2) Characteristics @ 25 °C are for reference only

c) Luminous Flux Characteristics (T_j = 85 °C)

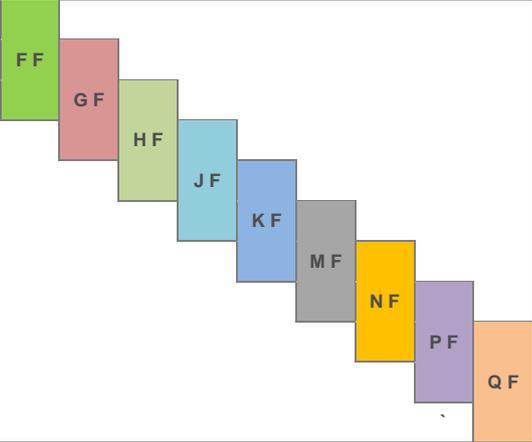
Sorting @ 700 mA (lm)			Calculated Minimum Flux ²⁾ (lm)				
Flux Rank	Flux Range ¹⁾	Sub Rank	@ 350 mA	@ 700 mA	@ 1050 mA	@ 1500 mA	@ 2000 mA
FF	150 ~ 210	FB, GB, HB	81	150	213	284	354
GF	170 ~ 230	GB, HB, JB	92	170	241	322	401
HF	190 ~ 250	HB, JB, KB	103	190	269	360	448
JF	210 ~ 270	JB, KB, MB	114	210	298	398	495
KF	230 ~ 290	KB, MB, NB	124	230	326	436	542
MF	250 ~ 310	MB, NB, PB	135	250	354	474	590
NF	270 ~ 330	NB, PB, QB	146	270	383	512	637
PF	290 ~ 350	PB, QB, RB	157	290	411	550	684
QF	310 ~ 370	QB, RB, SB	168	310	439	587	731
RF	330 ~ 390	RB, SB, TB	178	330	468	625	778
SF	350 ~ 410	SB, TB, UB	189	350	496	663	825
TF	370 ~ 430	TB, UB, VB	200	370	524	701	872
UF	390 ~ 450	UB, VB, WB	211	390	553	739	920
VF	410 ~ 470	VB, WB, YB	222	410	581	777	967
WF	430 ~ 490	WB, YB, ZB	232	430	609	815	1,014

Notes:

- 1) Samsung maintains measurement tolerance of: luminous flux = $\pm 7\%$, CRI = ± 3
- 2) Calculated minimum flux values at 350/1050/1500/2000mA are for reference only.

2. Product Code Information

1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
S	P	H	W	H	T	L	3	D	5	0	C	E	4	R	T	P	F

Digit	PKG Information	Code	Specification
1 2 3	Samsung Package High Power	SPH	
4 5	Color	WH	White
6	Product Version	T	
7 8	Product	L3	LH351 Series
9	Lens Type	D	Dome lens
10	Internal Code	5	LH351C
11	Not Defined	0	Default
12	CRI & Sorting Temperature	C D E G	Min. 70 Min. 75 Min. 80 Min. 90 85°C
13 14	Forward Voltage (V)	E 4	2.7~3.1 Bin Code: E2 2.7~2.9 G2 2.9~3.1
15 16	CCT (K)	W 0 V 0 U 0 T 0 R T Q T P T	2700 3000 3500 4000 5000 5700 6500 Bin Code: W1, W2, W3, W4, W5, W6, W7, W8, W9, WA, WB, WC, WD, WE, WF, WG, WM V1, V2, V3, V4, V5, V6, V7, V8, V9, VA, VB, VC, VD, VE, VF, VG, VM U1, U2, U3, U4, U5, U6, U7, U8, U9, UA, UB, UC, UD, UE, UF, UG, UM T1, T2, T3, T4, T5, T6, T7, T8, T9, TA, TB, TC, TD, TE, TF, TG, TM R1, R2, R3, R4 Q1, Q2, Q3, Q4 P1, P2, P3, P4 ★ : "0" (Whole bin), "P" (Quarter bin), or "M" (MacAdam 3-step ellipse bin)
17 18	Luminous Flux (lm)	FF GF HF JF KF MF NF PF QF	150 ~ 210 170 ~ 230 190 ~ 250 210 ~ 270 230 ~ 290 250 ~ 310 270 ~ 330 290 ~ 350 310 ~ 370 FB 150 ~ 170 GB 170 ~ 190 HB 190 ~ 210 JB 210 ~ 230 KB 230 ~ 250 MB 250 ~ 270 NB 270 ~ 290 PB 290 ~ 310 QB 310 ~ 330 RB 330 ~ 350 SB 350 ~ 370 
			Digit 17: Min. spec. Digit 18: The number of higher bin(s) from min. spec. e.g.: KB = 230~250 lm, KF = 230~290 lm

a) Luminous Flux Bins ($I_F = 700 \text{ mA}$, $T_j = 85 \text{ }^\circ\text{C}$)

CRI/ Nominal CCT (K)	Flux rank												
	FB	GB	HB	JB	KB	MB	NB	PB	QB	RB	SB	TB	
(min. flux)	150	170	190	210	230	250	270	290	310	330	350	370	
70	2700					SPHWHTL3D50CE4W ☆MF							
							SPHWHTL3D50CE4W ☆NF						
	3000						SPHWHTL3D50CE4V ☆NF						
								SPHWHTL3D50CE4V ☆PF					
	3500							SPHWHTL3D50CE4U ☆PF					
									SPHWHTL3D50CE4U ☆QF				
	4000							SPHWHTL3D50CE4T ☆PF					
									SPHWHTL3D50CE4T ☆QF				
	5000							SPHWHTL3D50CE4RTPF					
									SPHWHTL3D50CE4RTQF				
	5700							SPHWHTL3D50CE4QTPF					
									SPHWHTL3D50CE4QTQF				
75	6500						SPHWHTL3D50CE4PTPF						
								SPHWHTL3D50CE4PTQF					
	3000						SPHWHTL3D50DE4V ☆PF						
	3500						SPHWHTL3D50DE4U ☆PF						
	4000						SPHWHTL3D50DE4T ☆PF						
	5000						SPHWHTL3D50DE4RTPF						
								SPHWHTL3D50DE4RTQF					
	5700						SPHWHTL3D50DE4QTPF						
								SPHWHTL3D50DE4QTQF					
	80	2700					SPHWHTL3D50EE4W ☆MF						
		3000						SPHWHTL3D50EE4V ☆NF					
		3500						SPHWHTL3D50EE4U ☆NF					
4000						SPHWHTL3D50EE4T ☆MF							
							SPHWHTL3D50EE4T ☆NF						
5000							SPHWHTL3D50EE4RTNF						
								SPHWHTL3D50EE4RTPF					
5700							SPHWHTL3D50EE4QTNF						
								SPHWHTL3D50EE4QTPF					

"☆" can be "0" (Whole bin), "P" (Quarter bin), or "M" (MacAdam 3-step ellipse bin) of the color binning

a) Luminous Flux Bins ($I_F = 700 \text{ mA}$, $T_j = 85 \text{ }^\circ\text{C}$)

CRI/ Nominal CCT (K)	Flux rank											
	FB	GB	HB	JB	KB	MB	NB	PB	QB	RB	SB	TB
(min. flux)	150	170	190	210	230	250	270	290	310	330	350	370
90	SPHWHTL3D50GE4W☆HF											
	SPHWHTL3D50GE4W☆JF											
	SPHWHTL3D50GE4V☆JF											
	SPHWHTL3D50GE4U☆JF											
	SPHWHTL3D50GE4U☆KF											
	SPHWHTL3D50GE4T☆JF											
	SPHWHTL3D50GE4T☆KF											
	SPHWHTL3D50GE4RTKF											
SPHWHTL3D50GE4RTMF												

"☆" can be "0" (Whole bin), "P" (Quarter bin), or "M" (MacAdam 3-step ellipse bin) of the color binning

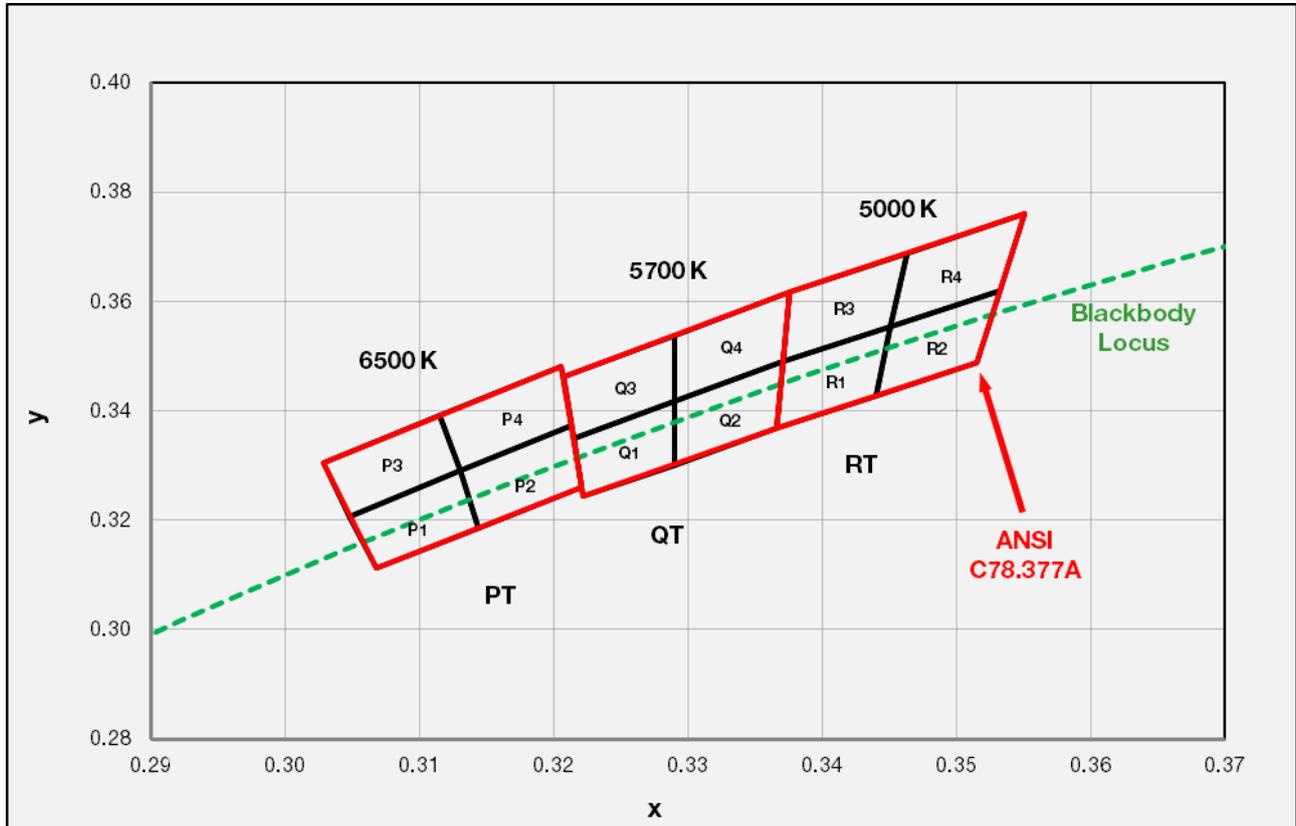
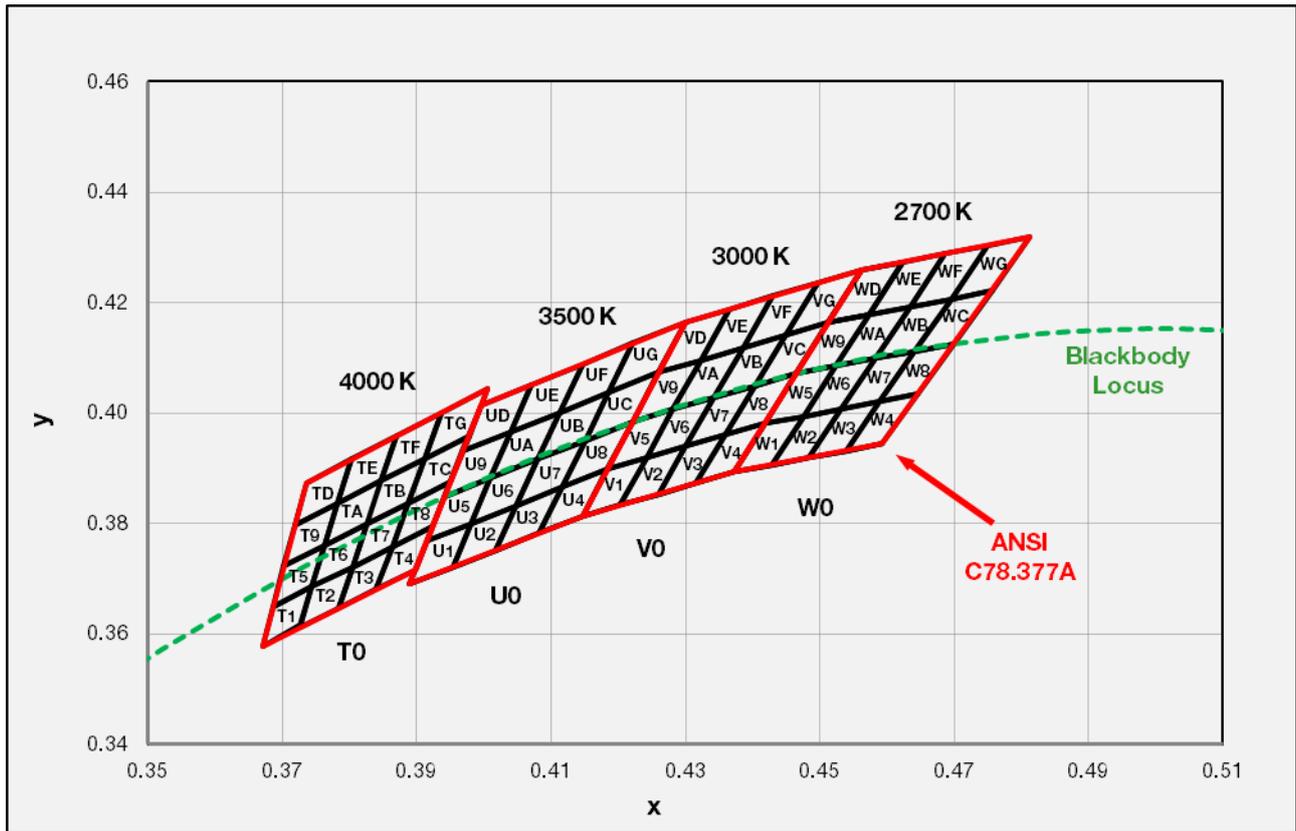
b) Color Bins ($I_F = 700 \text{ mA}$, $T_j = 85 \text{ }^\circ\text{C}$)

Nominal CCT (K)	CRI (R_a)	Color Rank	Chromaticity Bins
2700	70, 80, 90	☆0 (Whole bin)	1, 2, 3, 4, 5, 6, 7, 8, 9, A, B, C, D, E, F, G
		☆P (Quarter bin)	6, 7, A, B
		☆M (MacAdam 3-step)	M
3000, 3500, 4000	70, 80, 90	☆0 (Whole bin)	1, 2, 3, 4, 5, 6, 7, 8, 9, A, B, C, D, E, F, G
		☆P (Quarter bin)	6, 7, A, B
		☆M (MacAdam 3-step)	M
	75	☆0 (Whole bin)	1, 2, 3, 4, 5, 6, 7, 8, 9, A, B, C, D, E, F, G
5000, 5700	70, 75, 80, 90	☆T (ANSI bin)	1, 2, 3, 4
6500	70, 80, 90	☆T (ANSI bin)	1, 2, 3, 4

c) Voltage Bins ($I_F = 700 \text{ mA}$, $T_j = 85 \text{ }^\circ\text{C}$)

Nominal CCT (K)	CRI (R_a) Min.	Product Code	Voltage Rank	Voltage Bin	Voltage Range (V)
-	-	-	E4	E2	2.7 ~ 2.9
				G2	2.9 ~ 3.1

d) Chromaticity Region & Coordinates ($I_f = 700 \text{ mA}$, $T_j = 85 \text{ }^\circ\text{C}$)



d) Chromaticity Region & Coordinates ($I_F = 700 \text{ mA}$, $T_j = 85 \text{ }^\circ\text{C}$)

Region	CIE x	CIE y	Region	CIE x	CIE y
W rank (2700 K)					
W1	0.4373	0.3893	W9	0.4465	0.4071
	0.4418	0.3981		0.4513	0.4164
	0.4475	0.3994		0.4573	0.4178
	0.4428	0.3906		0.4523	0.4085
W2	0.4428	0.3906	WA	0.4523	0.4085
	0.4475	0.3994		0.4573	0.4178
	0.4532	0.4008		0.4634	0.4193
	0.4483	0.3919		0.4582	0.4099
W3	0.4483	0.3919	WB	0.4582	0.4099
	0.4532	0.4008		0.4634	0.4193
	0.4589	0.4021		0.4695	0.4207
	0.4538	0.3931		0.4641	0.4112
W4	0.4538	0.3931	WC	0.4641	0.4112
	0.4589	0.4021		0.4695	0.4207
	0.4646	0.4034		0.4756	0.4221
	0.4593	0.3944		0.4700	0.4126
W5	0.4418	0.3981	WD	0.4513	0.4164
	0.4465	0.4071		0.4562	0.4260
	0.4523	0.4085		0.4624	0.4274
	0.4475	0.3994		0.4573	0.4178
W6	0.4475	0.3994	WE	0.4573	0.4178
	0.4523	0.4085		0.4624	0.4274
	0.4582	0.4099		0.4687	0.4289
	0.4532	0.4008		0.4634	0.4193
W7	0.4532	0.4008	WF	0.4634	0.4193
	0.4582	0.4099		0.4687	0.4289
	0.4641	0.4112		0.4750	0.4304
	0.4589	0.4021		0.4695	0.4207
W8	0.4589	0.4021	WG	0.4695	0.4207
	0.4641	0.4112		0.4750	0.4304
	0.4700	0.4126		0.4813	0.4319
	0.4646	0.4034		0.4756	0.4221

Region	CIE x	CIE y	Region	CIE x	CIE y
V rank (3000 K)					
V1	0.4147	0.3814	V9	0.4221	0.3984
	0.4183	0.3898		0.4259	0.4073
	0.4242	0.3919		0.4322	0.4096
	0.4203	0.3833		0.4281	0.4006
V2	0.4203	0.3833	VA	0.4281	0.4006
	0.4242	0.3919		0.4322	0.4096
	0.4300	0.3939		0.4385	0.4119
	0.4259	0.3853		0.4342	0.4028
V3	0.4259	0.3853	VB	0.4342	0.4028
	0.4300	0.3939		0.4385	0.4119
	0.4359	0.3960		0.4449	0.4141
	0.4316	0.3873		0.4403	0.4049
V4	0.4316	0.3873	VC	0.4403	0.4049
	0.4359	0.3960		0.4449	0.4141
	0.4418	0.3981		0.4513	0.4164
	0.4373	0.3893		0.4465	0.4071
V5	0.4183	0.3898	VD	0.4259	0.4073
	0.4221	0.3984		0.4299	0.4165
	0.4281	0.4006		0.4364	0.4188
	0.4242	0.3919		0.4322	0.4096
V6	0.4242	0.3919	VE	0.4322	0.4096
	0.4281	0.4006		0.4364	0.4188
	0.4342	0.4028		0.4430	0.4212
	0.4300	0.3939		0.4385	0.4119
V7	0.4300	0.3939	VF	0.4385	0.4119
	0.4342	0.4028		0.4430	0.4212
	0.4403	0.4049		0.4496	0.4236
	0.4359	0.3960		0.4449	0.4141
V8	0.4359	0.3960	VG	0.4449	0.4141
	0.4403	0.4049		0.4496	0.4236
	0.4465	0.4071		0.4562	0.4260
	0.4418	0.3981		0.4513	0.4164

d) Chromaticity Region & Coordinates

Region	CIE x	CIE y	Region	CIE x	CIE y
U rank (3500 K)					
U1	0.3889	0.3690	U9	0.3941	0.3848
	0.3915	0.3768		0.3968	0.3930
	0.3981	0.3800		0.4040	0.3966
	0.3953	0.3720		0.4010	0.3882
U2	0.3953	0.3720	UA	0.4010	0.3882
	0.3981	0.3800		0.4040	0.3966
	0.4048	0.3832		0.4113	0.4001
	0.4017	0.3751		0.4080	0.3916
U3	0.4017	0.3751	UB	0.4080	0.3916
	0.4048	0.3832		0.4113	0.4001
	0.4116	0.3865		0.4186	0.4037
	0.4082	0.3782		0.4150	0.3950
U4	0.4082	0.3782	UC	0.4150	0.3950
	0.4116	0.3865		0.4186	0.4037
	0.4183	0.3898		0.4259	0.4073
	0.4147	0.3814		0.4221	0.3984
U5	0.3915	0.3768	UD	0.3968	0.3930
	0.3941	0.3848		0.3996	0.4015
	0.4010	0.3882		0.4071	0.4052
	0.3981	0.3800		0.4040	0.3966
U6	0.3981	0.3800	UE	0.4040	0.3966
	0.4010	0.3882		0.4071	0.4052
	0.4080	0.3916		0.4146	0.4089
	0.4048	0.3832		0.4113	0.4001
U7	0.4048	0.3832	UF	0.4113	0.4001
	0.4080	0.3916		0.4146	0.4089
	0.4150	0.3950		0.4222	0.4127
	0.4116	0.3865		0.4186	0.4037
U8	0.4116	0.3865	UG	0.4186	0.4037
	0.4150	0.3950		0.4222	0.4127
	0.4221	0.3984		0.4299	0.4165
	0.4183	0.3898		0.4259	0.4073

Region	CIE x	CIE y	Region	CIE x	CIE y
T rank (4000 K)					
T1	0.3670	0.3578	T9	0.3702	0.3722
	0.3726	0.3612		0.3763	0.3760
	0.3744	0.3685		0.3782	0.3837
	0.3686	0.3649		0.3719	0.3797
T2	0.3726	0.3612	TA	0.3763	0.3760
	0.3783	0.3646		0.3825	0.3798
	0.3804	0.3721		0.3847	0.3877
	0.3744	0.3685		0.3782	0.3837
T3	0.3783	0.3646	TB	0.3825	0.3798
	0.3840	0.3681		0.3887	0.3836
	0.3863	0.3758		0.3912	0.3917
	0.3804	0.3721		0.3847	0.3877
T4	0.3840	0.3681	TC	0.3887	0.3837
	0.3898	0.3716		0.3950	0.3875
	0.3924	0.3794		0.3978	0.3958
	0.3863	0.3758		0.3912	0.3917
T5	0.3686	0.3649	TD	0.3719	0.3797
	0.3744	0.3685		0.3782	0.3837
	0.3763	0.3760		0.3802	0.3916
	0.3702	0.3722		0.3736	0.3874
T6	0.3744	0.3685	TE	0.3782	0.3837
	0.3804	0.3721		0.3847	0.3877
	0.3825	0.3798		0.3869	0.3958
	0.3763	0.3760		0.3802	0.3916
T7	0.3804	0.3721	TF	0.3847	0.3877
	0.3863	0.3758		0.3912	0.3917
	0.3887	0.3836		0.3937	0.4001
	0.3825	0.3798		0.3869	0.3958
T8	0.3863	0.3758	TG	0.3912	0.3917
	0.3924	0.3794		0.3978	0.3958
	0.3950	0.3875		0.4006	0.4044
	0.3887	0.3836		0.3937	0.4001

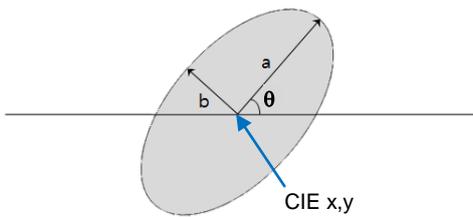
d) Chromaticity Region & Coordinates

Region	CIE x	CIE y
R rank (5000 K)		
R1	0.3371	0.3490
	0.3451	0.3554
	0.3440	0.3427
	0.3366	0.3369
R2	0.3451	0.3554
	0.3533	0.3620
	0.3515	0.3487
	0.3440	0.3427
R3	0.3376	0.3616
	0.3463	0.3687
	0.3451	0.3554
	0.3371	0.3490
R4	0.3463	0.3687
	0.3551	0.3760
	0.3533	0.3620
	0.3451	0.3554

Region	CIE x	CIE y
Q rank (5700 K)		
Q1	0.3215	0.3350
	0.3290	0.3417
	0.3290	0.3300
	0.3222	0.3243
Q2	0.3290	0.3417
	0.3371	0.3490
	0.3366	0.3369
	0.3290	0.3300
Q3	0.3207	0.3462
	0.3290	0.3538
	0.3290	0.3417
	0.3215	0.3350
Q4	0.3290	0.3538
	0.3376	0.3616
	0.3371	0.3490
	0.3290	0.3417

Region	CIE x	CIE y
P rank (6500 K)		
P1	0.3068	0.3113
	0.3144	0.3186
	0.3130	0.3290
	0.3048	0.3207
P2	0.3144	0.3186
	0.3221	0.3261
	0.3213	0.3373
	0.3130	0.3290
P3	0.3048	0.3207
	0.3130	0.3290
	0.3115	0.3391
	0.3028	0.3304
P4	0.3130	0.3290
	0.3213	0.3373
	0.3205	0.3481
	0.3115	0.3391

e) MacAdam 3-step Ellipse ($I_F = 1050 \text{ mA}$, $T_j = 85 \text{ }^\circ\text{C}$)



Nom. CCT (K)	Color Rank	Center		Rotation Angle θ ($^\circ$)	a	b
		CIE x	CIE y			
2700	WM	0.4578	0.4101	53.70	0.0081	0.0042
3000	VM	0.4338	0.4030	53.22	0.0083	0.0041
3500	UM	0.4073	0.3917	54.00	0.0093	0.0041
4000	TM	0.3818	0.3797	53.72	0.0094	0.0040

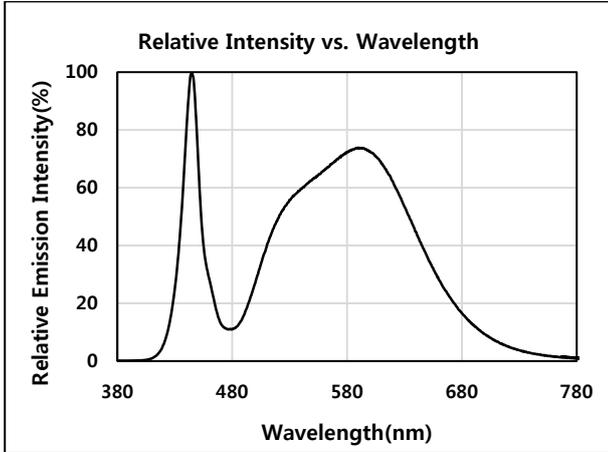
Note:

Samsung maintains measurement tolerance of: $C_x, C_y = \pm 0.005$

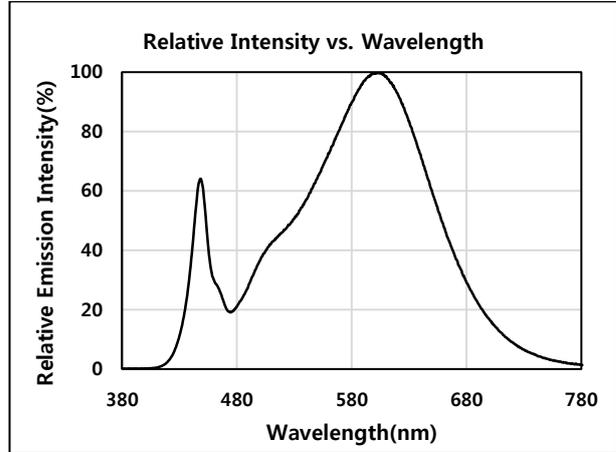
3. Typical Characteristics Graphs

a) Spectrum Distribution ($I_F = 700 \text{ mA}$, $T_j = 85 \text{ }^\circ\text{C}$)

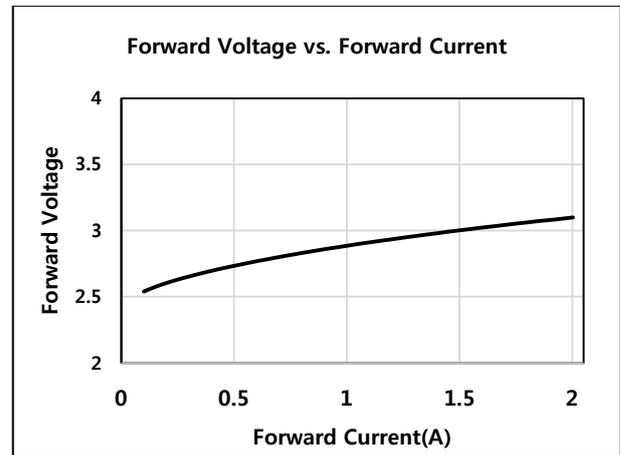
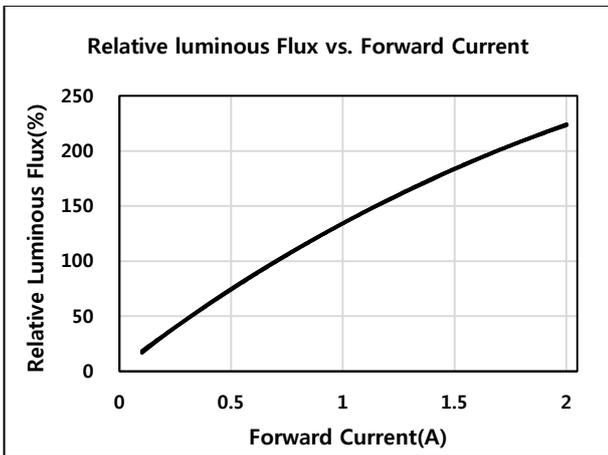
Cool White (CRI70)



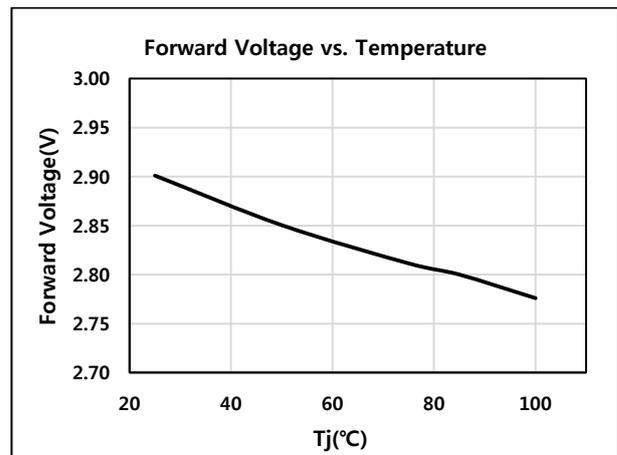
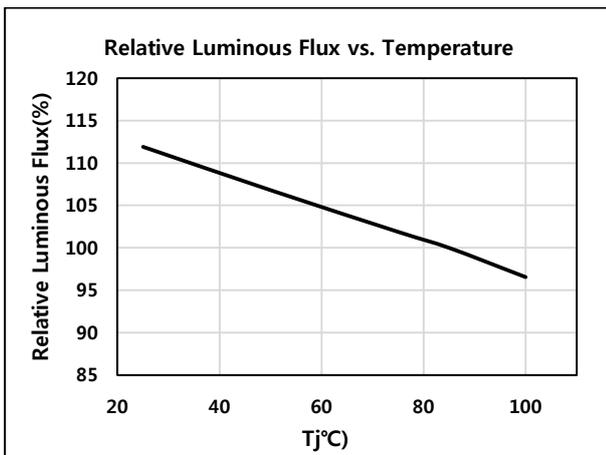
Warm White (CRI80)



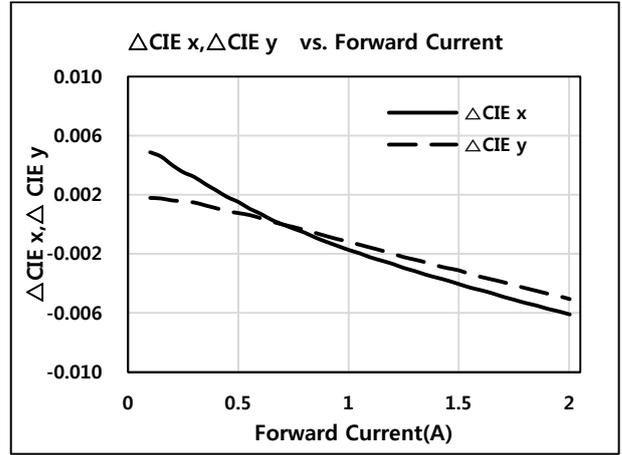
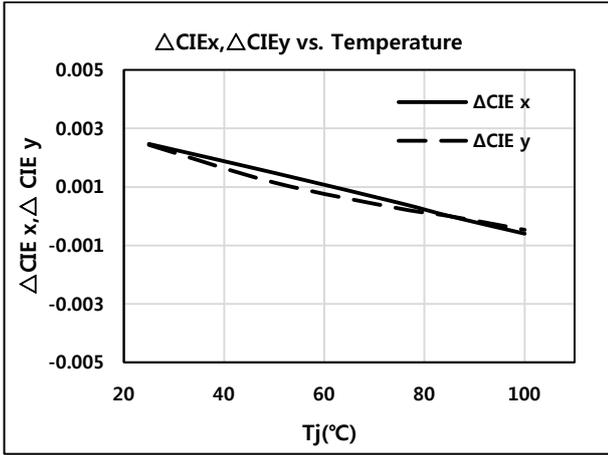
b) Forward Current Characteristics ($T_j = 85 \text{ }^\circ\text{C}$)



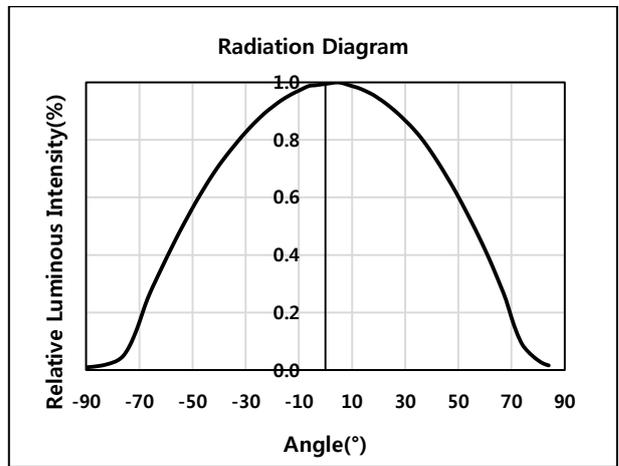
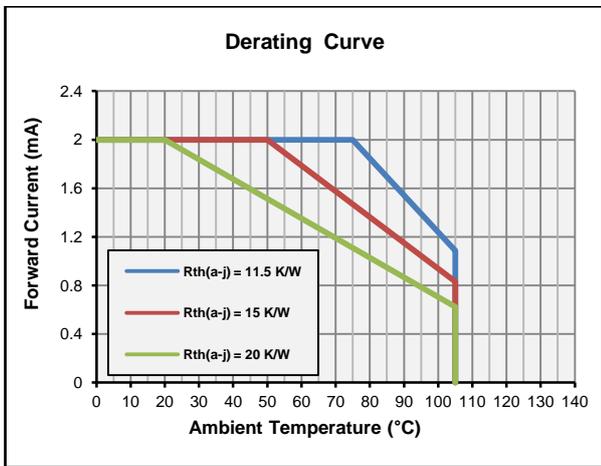
c) Temperature Characteristics ($I_F = 700 \text{ mA}$)



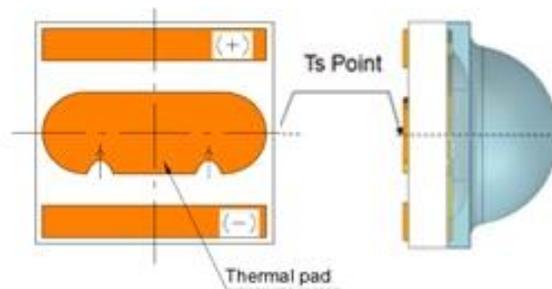
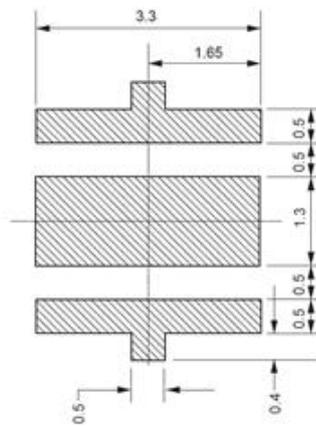
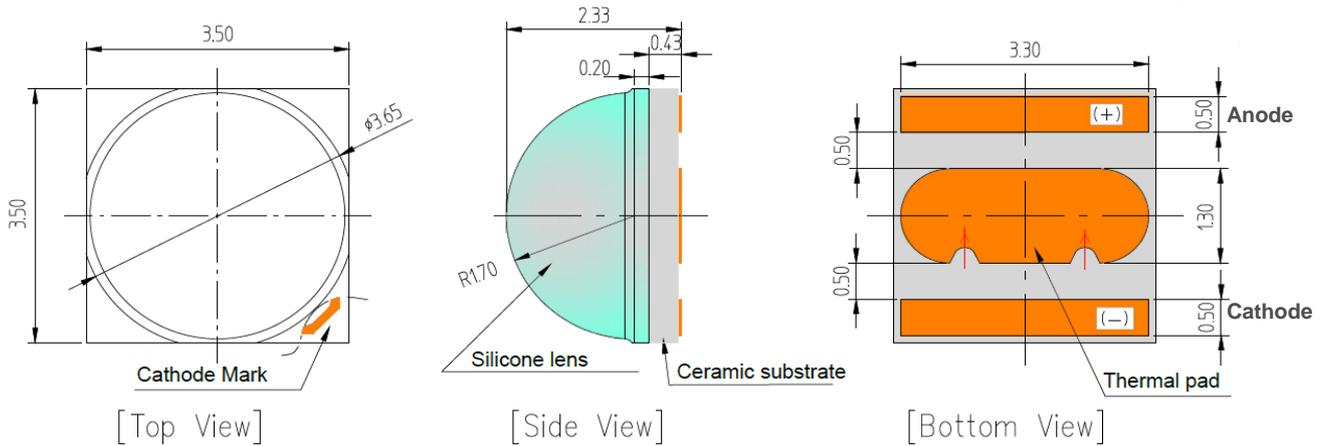
d) Color Shift Characteristics ($I_F = 700 \text{ mA}$, $T_j = 85 \text{ }^\circ\text{C}$)



e) Derating Curve and Beam Angle Characteristics ($I_F = 700 \text{ mA}$, $T_j = 25 \text{ }^\circ\text{C}$)



4. Outline Drawing & Dimension



- Measurement unit: mm
- Tolerance: ± 0.13 mm

Recommended Soldering Pattern

Notes:

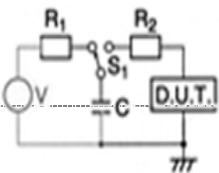
- 1) This LED has built-in ESD protection device(s) connected in parallel to LED chip(s).
- 2) The thermal pad is electrically isolated from the anode and cathode contact pads.
- 3) T_s point and measurement method:
 - ① Measure the nearest point to thermal pad as shown above. If necessary, remove PSR of PCB to reach T_s point.
 - ② All pads must be soldered to the PCB to dissipate heat properly, otherwise the LED can be damaged.

Precautions:

- 1) Pressure on the LEDs will influence to the reliability of the LEDs. Precautions should be taken to avoid strong pressure on the LEDs. Do not put stress on the LEDs during heating.
- 2) Re-soldering should not be done after the LEDs have been soldered. If re-soldering is unavoidable, LED's characteristics should be carefully checked before and after such repair.
- 3) Do not stack assembled PCBs together. Since materials of LEDs is soft, abrasion between two PCB assembled with LED might cause catastrophic failure of the LEDs.

5. Reliability Test Items & Conditions

a) Test Items

Test Item	Test Condition	Test Hour / Cycle	Sample Size
Room Temperature Life Test	25 °C, Maximum Rated Drive Current	1000 h	22
High Temperature Life Test	85 °C, Maximum Rated Drive Current	1000 h	22
High Temperature Humidity Life Test	85 °C, 85 % RH, Maximum Rated Drive Current	1000 h	22
Low Temperature Life Test	-40 °C, Maximum Rated Drive Current	1000 h	22
Powered Temperature Cycle	-45 °C / 20 min ↔ 85 °C / 20 min, sweep 100 min cycle on/off: each 5 min, Maximum Rated Drive Current	100 cycles	11
Temperature Cycling	-45 °C / 15 min ↔ 125 °C / 15 min temperature change within 5 min	500 cycles	100
High Temperature Storage	120 °C	1000 h	11
Low Temperature Storage	-40 °C	1000 h	11
ESD (HBM)	 <p> R_1: 10 MΩ R_2: 1.5 kΩ C: 100 pF V: ± 8 kV </p>	5 times	30
ESD (MM)	<p> R_1: 10 MΩ R_2: 0 C: 200 pF V: ± 0.8 kV </p>	5 times	30
Vibration Test	20~2000~20 Hz, 200 m/s ² , sweep 4 min X, Y, Z 3 direction, each 1 cycle	4 cycles	11

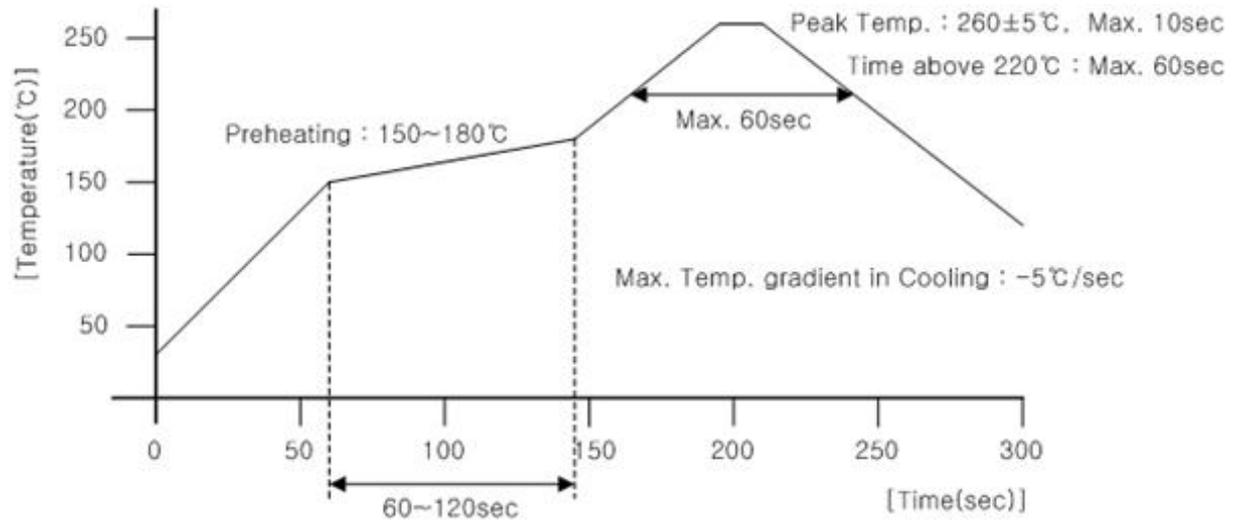
b) Criteria for Judging the Damage

Item	Symbol	Test Condition ($T_j = 25$ °C)	Limit	
			Min.	Max.
Forward Voltage	V_F	$I_F = 700$ mA	Init. Value * 0.9	Init. Value * 1.1
Luminous Flux	Φ_v	$I_F = 700$ mA	Init. Value * 0.7	Init. Value * 1.1

6. Soldering Conditions

a) Reflow Conditions (Pb free)

Reflow frequency: 2 times max.

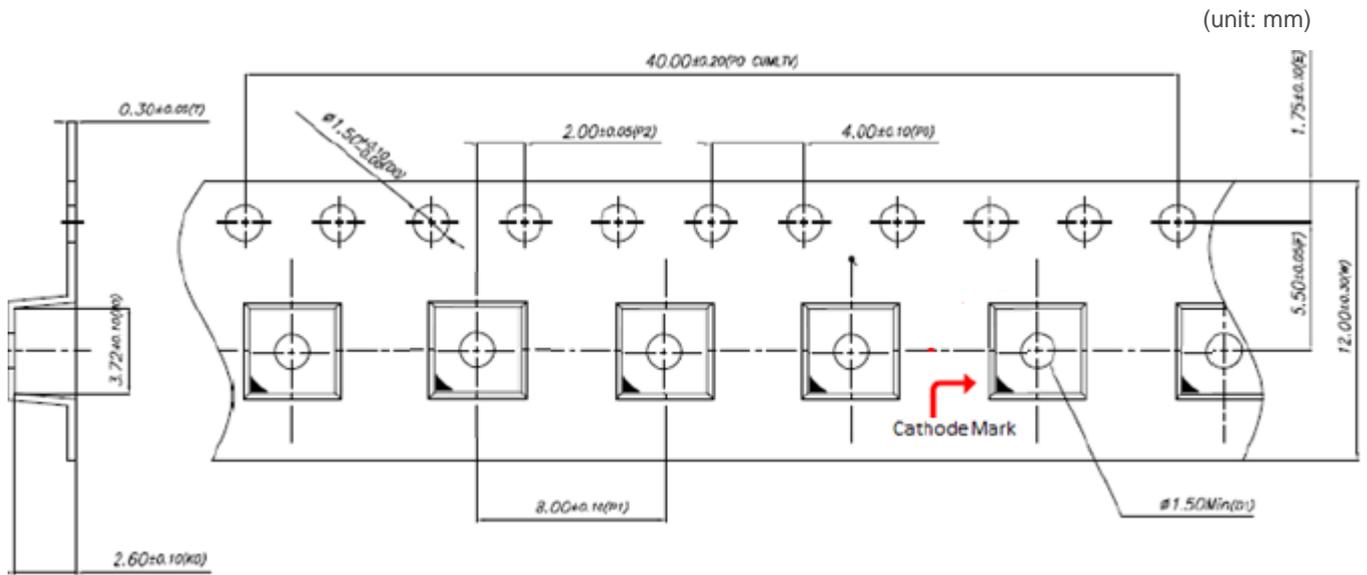


b) Manual Soldering Conditions

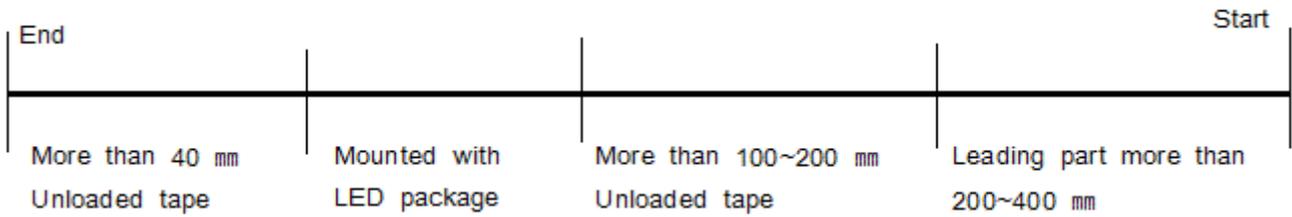
Not more than 5 seconds @ max. 300 °C, under soldering iron.

7. Tape & Reel

a) Taping Dimension

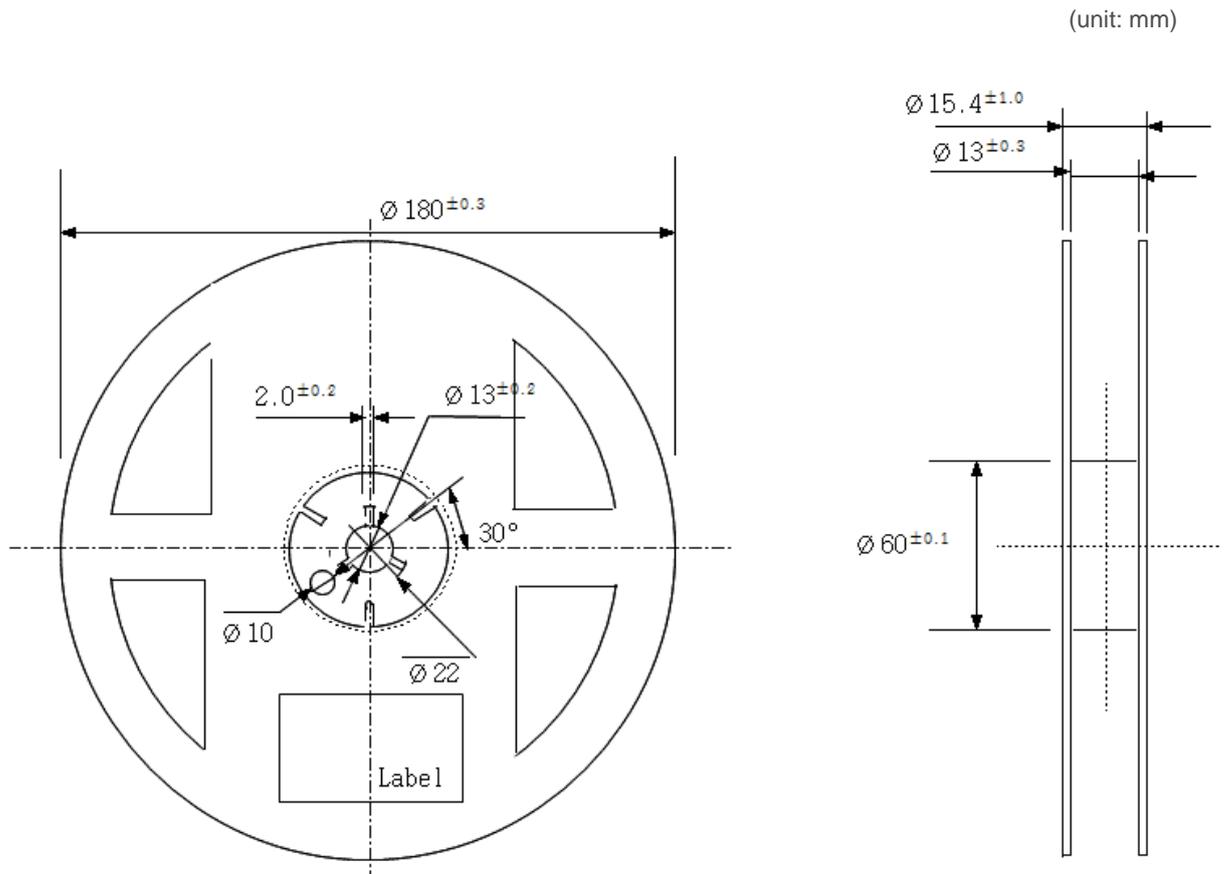


Taping Direction



Taping Direction

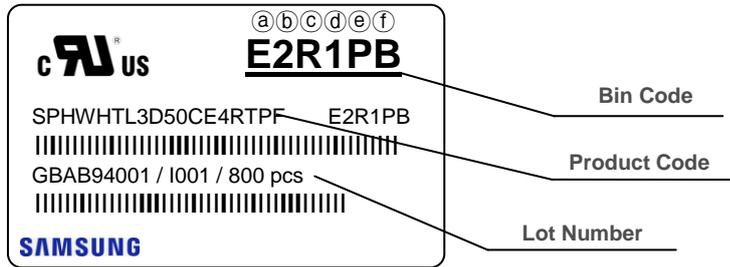
b) Reel Dimension

**Notes:**

- 1) Quantity: The quantity/reel is 800 pcs
- 2) Cumulative tolerance: Cumulative tolerance / 10 pitches is ± 0.2 mm
- 3) Adhesion strength of cover tape: Adhesion strength is 0.1-0.7 N when the cover tape is turned off from the carrier tape at 10° angle to the carrier tape
- 4) Packaging: P/N, Manufacturing data code no. and quantity are indicated on the aluminum packing bag

8. Label Structure

a) Label Structure



Note: Denoted bin code and product code above is only an example (see description on page 7)

Bin Code:

- ⒶⒷ: Forward Voltage bin (refer to 9 page)
- ⒸⒹ: Chromaticity bin (refer to 9 page)
- ⒺⒻ: Luminous Flux bin (refer to 7 page)

b) Lot Number

The lot number is composed of the following characters:



①②③④⑤⑥⑦⑧⑨ / IⒶⒷⒸ / 800 pcs

- ①, ② : Production site (GB : Nanchang, China)
- ③ : Product state (A: Normal, B: Bulk, C: First Production, R: Reproduction, S: Sample)
- ④ : Year (Y: 2014, Z: 2015, A: 2016, B: 2017, C: 2018, D: 2019 ...)
- ⑤ : Month (1~9, A, B, C)
- ⑥ : Day (1~9, A, B~V)
- ⑦⑧⑨ : Product serial number (001 ~ 999)
- ⒶⒷⒸ : Reel number (001 ~ 999)

9. Packing Structure

a) Packing Process

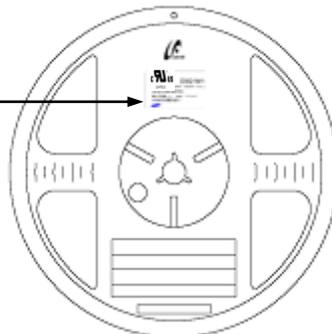
Reel

c **RL** **us** **E2R1PB**

SPHWHTL3D50CE4RTPF E2R1PB

GBAB94001 / I001 / 800 pcs

SAMSUNG



Aluminum Vinyl Packing Bag

c **RL** **us** **E2R1PB**

SPHWHTL3D50CE4RTPF E2R1PB

GBAB94001 / I001 / 800 pcs

SAMSUNG



Outer Box

Material: Paper SW(B)

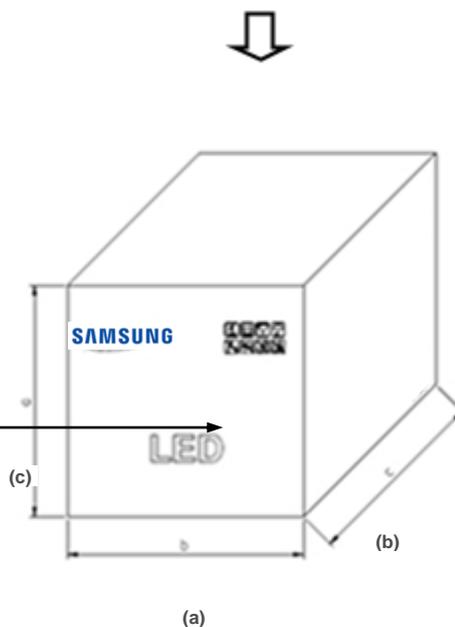
Type	Size (mm)			Note
	(a)	(b)	(c)	
7 inch (L)	245 ± 5	220 ± 5	182 ± 5	Up to 8 reels
7 inch (S)	245 ± 5	220 ± 5	86 ± 5	Up to 4 reels

c **RL** **us** **E2R1PB**

SPHWHTL3D50CE4RTPF E2R1PB

GBAB94001 / I000 / 6,400 pcs

SAMSUNG



b) Aluminum Vinyl Packing Bag



CAUTION

This bag contains
MOISTURE SENSITIVE DEVICES

LEVEL
2a



E2R1PB

SPHWHTL3D50CE4RTPF E2R1PB
 GBAB94001 / 1001 / 800 pcs

SAMSUNG





ATTENTION

OBSEVE PRECAUTIONS
FOR HANDLING
ELECTROSTATIC
SENSITIVE
DEVICES



주의 사항

이 알루미늄 지퍼 백은 습기 및 정전기로부터 제품을 보호하기 위하여 제작되었습니다. 개봉 후에는 즉시 솔더 작업을 실시하는 것을 권장합니다.

습기 및 정전기로부터 제품을 보호 하기 위해서 개봉 후 사용하지 않는 자재는 본 팩에 넣어 보관 하시기 바랍니다. 사용하지 않는 자재를 본 팩에 넣을 때는 반드시 동봉된 드라이 팩과 함께 넣고 지퍼부분을 완전하게 밀봉하여 주시기 바랍니다.

Important

This Al Zipper bag is designed to protect the enclosed products from moisture and ESD. Once opened, the products should be soldered onto the printed circuit board immediately. When not in use, please do not leave the products unprotected by the Al Zipper Bag. To repack unused products., please ensure the zip-lock is completely sealed with the dry pack left inside.

c) Silica Gel & Humidity Indicator Card inside Aluminum Vinyl Bag



HUMISAFE™

10% 20% 30% 40% 50% 60%



READ AT TOP OF GREEN COLOR
CHANGE BETWEEN YELLOW AND GREEN

**HUMIDITY INDICATOR
COBALT-FREE**

Warning if Green
Change Desiccant

GP&E Co., Ltd.
6CF-60NS

10. Precautions in Handling & Use

- 1) For over-current protection, users are recommended to apply resistors connected in series with the LEDs to mitigate sudden change of the forward current caused by shift of forward voltage.
- 2) This device should not be used in any type of fluid such as water, oil, organic solvent, etc. When cleaning is required, IPA is recommended as the cleaning agent. Some solvent-based cleaning agent may damage the silicone resins used in the device.
- 3) When the device is in operation, the forward current should be carefully determined considering the maximum ambient temperature and corresponding junction temperature.
- 4) LEDs must be stored in a clean environment. If the LEDs are to be stored for three months or more after being shipped from Samsung, they should be packed with a nitrogen-filled container (shelf life of sealed bags is 12 months at temperature 0~40 °C, 0~90 % RH).
- 5) After storage bag is opened, device subjected to soldering, solder reflow, or other high temperature processes must be:
 - a. Mounted within 672 hours (28 days) at an assembly line with a condition of no more than 30 °C / 60 % RH, or
 - b. Stored at <10 % RH
- 6) Repack unused devices with anti-moisture packing, fold to close any opening and then store in a dry place.
- 7) Devices require baking before mounting, if humidity card reading is >60 % at 23 ± 5 °C.
- 8) Devices must be baked for 1 hour at 60 ± 5 °C, if baking is required.
- 9) The LEDs are sensitive to the static electricity and surge current. It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs. If voltage exceeding the absolute maximum rating is applied to LEDs, it may cause damage or even destruction to LED devices. Damaged LEDs may show some unusual characteristics such as increase in leakage current, lowered turn-on voltage, or abnormal lighting of LEDs at low current.
- 10) VOCs (Volatile Organic Compounds) can be generated from adhesives, flux, hardener or organic additives used in luminaires (fixtures). Transparent LED silicone encapsulant is permeable to those chemicals and they may lead to a discoloration of encapsulant when they exposed to heat or light. This phenomenon can cause a significant loss of light emitted (output) from the luminaires. In order to prevent these problems, we recommend users to know the physical properties of materials used in luminaires and they must be carefully selected.

Legal and additional information.

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